

#### 3.2x1.6mm SMD CHIP LED LAMP

Part Number: KP-3216SECK

Super Bright Orange

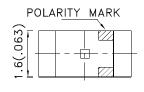
#### **Features**

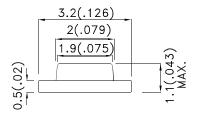
- 3.2mmx1.6mm SMT LED, 1.1mm thickness.
- Low power consumption.
- Wide viewing angle.
- Ideal for backlight and indicator.
- Various colors and lens types available.
- Package: 2000pcs / reel.
- Moisture sensitivity level : level 3.
- RoHS compliant.

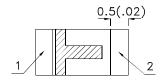
### Description

The Super Bright Orange device is made with AlGaInP (on GaAs substrate) light emitting diode chip.

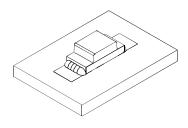
### **Package Dimensions**











- 1. All dimensions are in millimeters (inches).
- 2. Tolerance is ±0.2(0.0079") unless otherwise noted.
- 3. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice. 4.The device has a single mounting surface. The device must be mounted according to the specifications.

SPEC NO: DSAB8603 **REV NO: V.11** DATE: AUG/17/2010 PAGE: 1 OF 5 APPROVED: WYNEC **CHECKED: Allen Liu** DRAWN: F.F.Zhou ERP: 1203000396

### **Selection Guide**

Part No.	Dice	Lens Type	lv (mcd) [2] @ 20mA		Viewing Angle [1]
			Min.	Тур.	201/2
KP-3216SECK	Super Bright Orange (AlGaInP)	Water Clear	120	250	120°

- Notes: 1.  $\theta$ 1/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value. 2. Luminous intensity/ luminous Flux: +/-15%.

### Electrical / Optical Characteristics at TA=25°C

	•					
Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Super Bright Orange	610		nm	IF=20mA
λD [1]	Dominant Wavelength	Super Bright Orange	601		nm	IF=20mA
Δλ1/2	Spectral Line Half-width	Super Bright Orange	29		nm	IF=20mA
С	Capacitance	Super Bright Orange	15		pF	VF=0V;f=1MHz
VF [2]	Forward Voltage	Super Bright Orange	2.1	2.5	V	I==20mA
lr	Reverse Current	Super Bright Orange		10	uA	V <sub>R</sub> =5V

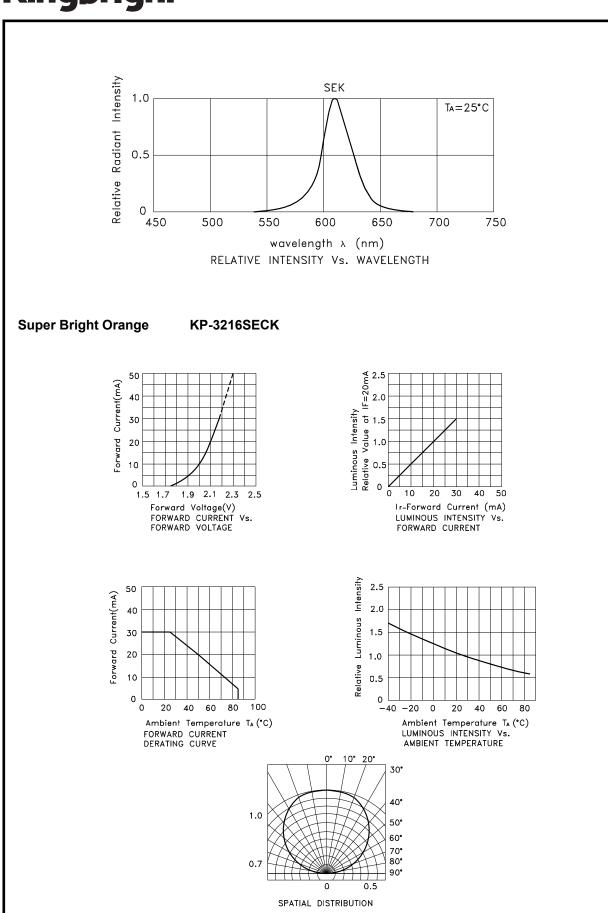
- Notes: 1.Wavelength: +/-1nm. 2. Forward Voltage: +/-0.1V.

#### Absolute Maximum Ratings at TA=25°C

Parameter	Super Bright Orange		
Power dissipation	75	mW	
DC Forward Current	30	mA	
Peak Forward Current [1]	195	mA	
Reverse Voltage	5	V	
Operating Temperature	-40°C To +85°C		
Storage Temperature	-40°C To +85°C		

Note: 1. 1/10 Duty Cycle, 0.1ms Pulse Width.

SPEC NO: DSAB8603 **REV NO: V.11** DATE: AUG/17/2010 PAGE: 2 OF 5 APPROVED: WYNEC **CHECKED: Allen Liu** DRAWN: F.F.Zhou ERP: 1203000396



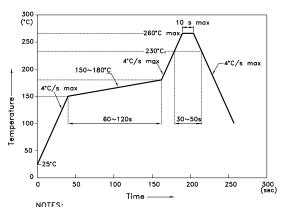
 SPEC NO: DSAB8603
 REV NO: V.11
 DATE: AUG/17/2010
 PAGE: 3 OF 5

 APPROVED: WYNEC
 CHECKED: Allen Liu
 DRAWN: F.F.Zhou
 ERP: 1203000396

#### **KP-3216SECK**

Reflow soldering is recommended and the soldering profile is shown below. Other soldering methods are not recommended as they might cause damage to the product.

Reflow Soldering Profile For Lead-free SMT Process.



- NOTES:

  1.We recommend the reflow temperature 245°C(+/-5°C). The maximum soldering temperature should be limited to 260°C.

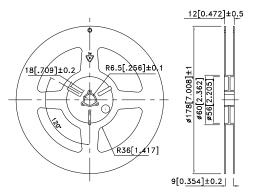
  2.Don't cause stress to the epoxy resin while it is exposed to high temperature.
  - to high temperature.

    3.Number of reflow process shall be 2 times or less.

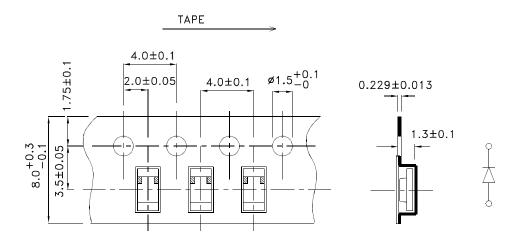
## Recommended Soldering Pattern (Units: mm; Tolerance: ± 0.1)



### **Reel Dimension**

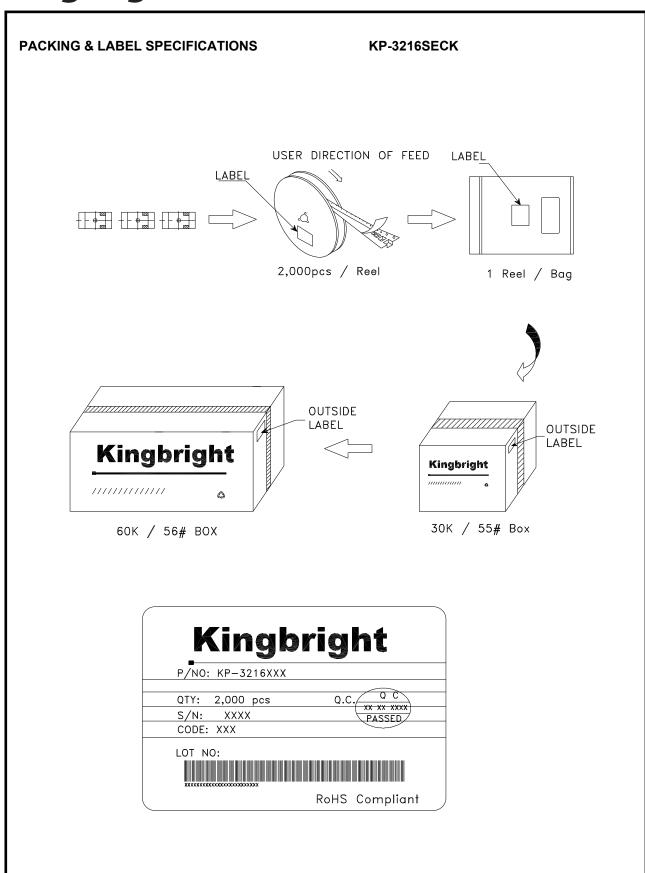


## Tape Dimensions (Units : mm)



 SPEC NO: DSAB8603
 REV NO: V.11
 DATE: AUG/17/2010
 PAGE: 4 OF 5

 APPROVED: WYNEC
 CHECKED: Allen Liu
 DRAWN: F.F.Zhou
 ERP: 1203000396



SPEC NO: DSAB8603 APPROVED: WYNEC REV NO: V.11 CHECKED: Allen Liu DATE: AUG/17/2010 DRAWN: F.F.Zhou PAGE: 5 OF 5 ERP: 1203000396